

Features

- High isolation 5000 VRMS
- CTR flexibility available see order information
- DC input with transistor output
- External Creepage ≥ 7.5mm (S/SL Type)
- External Creepage ≥ 8.0mm (SLM Type)
- Operating temperature range 55 °C to 110 °C
- Regulatory Approvals
 - UL UL1577 (E364000)
 - VDE EN60747-5-5(VDE0884-5)
 - CQC GB4943.1, GB8898
 - IEC60065, IEC60950

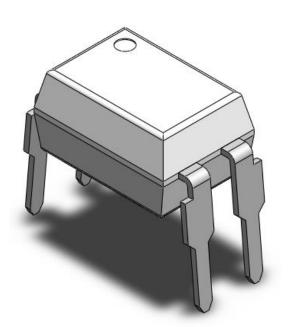
Description

The CT817 series consists of a photo transistor optically coupled to a gallium arsenide Infraredemitting diode in a 4-lead DIP package different lead forming options.

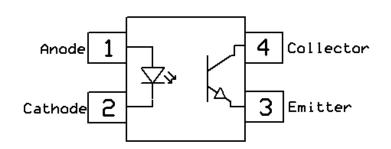
Applications

- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

Package Outline



Schematic



Note: Different lead forming options available. See package

dimension.



Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
Viso	Isolation voltage (AC, 1 minute)	5000	VRMS	
Ртот	Total power dissipation	200	mW	
Topr	Operating temperature	-55 ~ +110	°C	
Tstg	Storage temperature	-55 ~ +150	°C	
Tso∟	Soldering temperature	260	°C	
Emitter				
IF	Forward current	60	mA	
IF(TRANS)	Peak transient current (≤1µs P.W,300pps)	1	А	
VR	Reverse voltage	6	V	
PD	Emitter power dissipation	100	mW	
Detector	-			
PD	Detector power dissipation	150	mW	
B _{VCEO}	Collector-Emitter Breakdown Voltage	35	V	
BVECO	Emitter-Collector Breakdown Voltage	6	V	
lc	Collector Current	50	mA	



Electrical Characteristics $T_A = 25^{\circ}C$ (unless otherwise specified)

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	I _F =10mA	-	1.24	1.4	V	
I _R	Reverse Current	$V_R = 6V$	-	-	5	μA	
CIN	Input Capacitance	f= 1MHz	-	10	30	pF	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
BVCEO	Collector-Emitter Breakdown	Ic= 100μA	35	-	-	V	
B _{VECO}	Emitter-Collector Breakdown	I _E = 100μA	6	-	-	V	
ICEO	Collector-Emitter Dark Current	V _{CE} = 20V, I _F =0mA	-	-	100	nA	

Transfer Characteristics

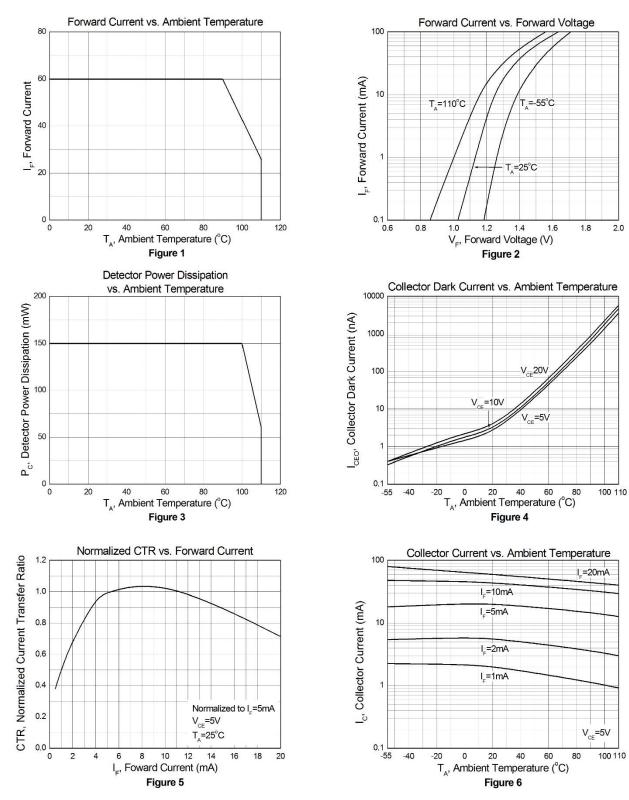
Symbol	Parameters		Test Conditions	Min	Тур	Max	Units	Notes
	Current Transfer Ratio CT81 CT81	CT817	I⊧= 5mA, Vce= 5V	50	-	600	%	
		CT817A		80	-	160		
CTR		CT817B		130	-	260		
		CT817C		200	-	400		
		CT817D		300	-	600		
	Collector-Emitter Satura	ation	I _F = 20mA, I _C = 1mA		0.1	0.2	V	
V _{CE(SAT)}	Voltage		1F- 2011A, 1C- 1111A	-	0.1	0.2	v	
Rio	Isolation Resistance		V _{IO} = 500V _{DC}	5x10 ¹⁰	-	-	Ω	
Сю	Isolation Capacitance		f= 1MHz	-	0.25	1	pF	

Switching Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
tr	Rise Time	I _C = 2mA, V _{CE} = 2V	-	6	18		
t _f	Fall Time	RL= 100Ω	-	8	18	μs	



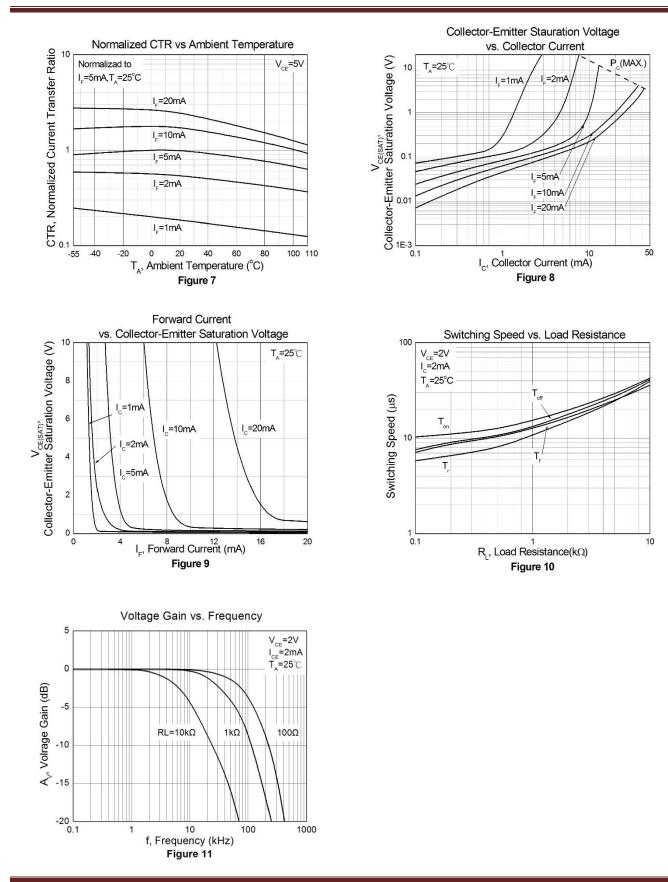
Typical Characteristic Curves





CT817 Series







Test Circuit

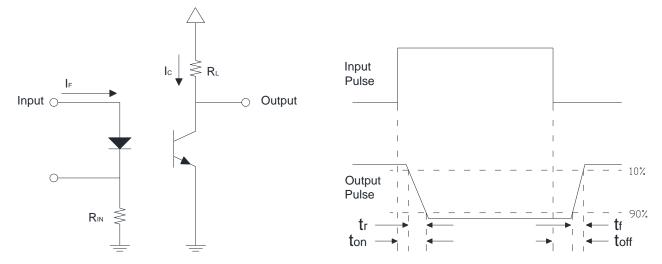
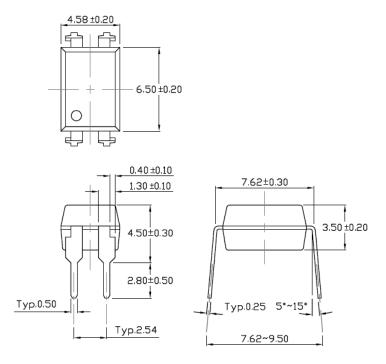


Figure 12: Switching Time Test Circuits

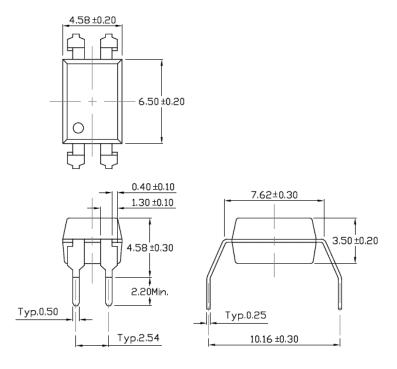


Package Dimension Dimensions in mm unless otherwise stated

Standard DIP – Through Hole

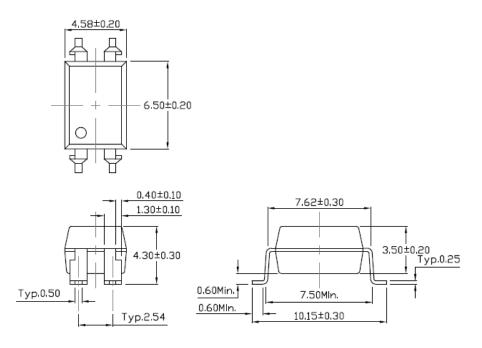


Gullwing (400mil) Lead Forming – Through Hole (M Type)

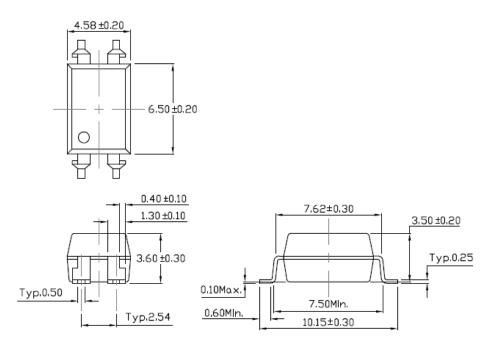




Surface Mount Lead Forming (S Type)

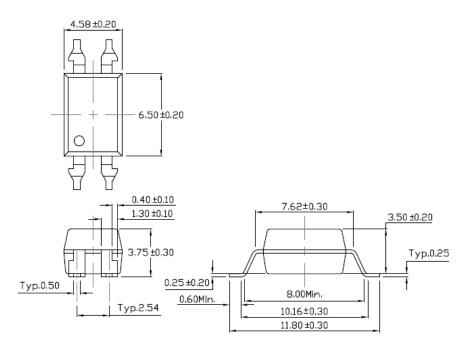


Surface Mount (Low Profile) Lead Forming (SL Type)





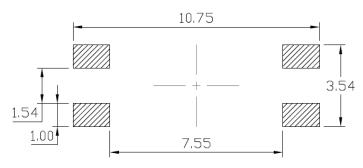
Surface Mount (Gullwing) Lead Forming (SLM Type)



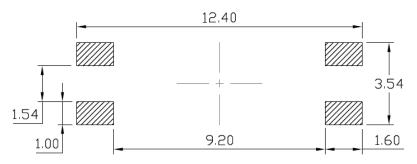


Recommended Solder Mask Dimensions in mm unless otherwise stated

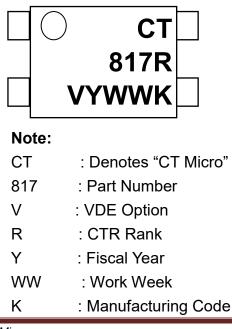
Surface Mount Lead Forming & Surface Mount (Low Profile) Lead Forming



Surface Mount (Gullwing) Lead Forming



Marking Information





Ordering Information

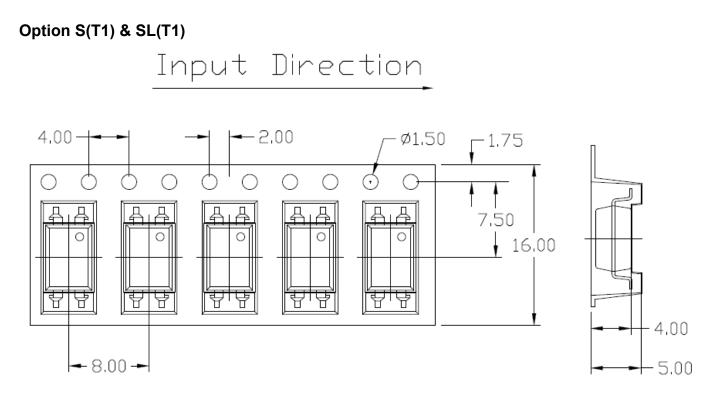
CT817X(V)(Y)(Z)-HG

- X = Part No. (X=A, B, C, D or None)
- V = VDE Option (V or None)
- Y = Lead form option (S, SL, M, SLM or none)
- Z = Tape and reel option (T1, T2, T3, T4 or none)
- H = Lead frame option (H: Iron, None: Copper)
- G= Material option (G: Green, None: Non-green)

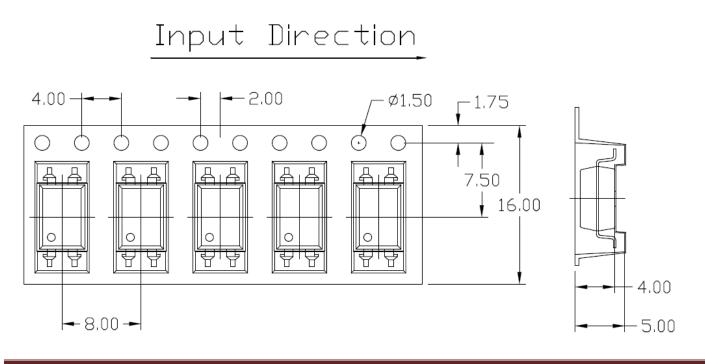
Option	Description	Quantity
None	Standard 4 Pin Dip	100 Units/Tube
М	Gullwing (400mil) Lead Forming	100 Units/Tube
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1500 Units/Reel
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1500 Units/Reel
S(T3)	Surface Mount Lead Forming – With Option 3 Taping	1000 Units/Reel
S(T4)	Surface Mount Lead Forming – With Option 4 Taping	1000 Units/Reel
SL(T1)	Surface Mount (Low Profile) Lead Forming– With Option 1 Taping	1500 Units/Reel
SL(T2)	Surface Mount (Low Profile) Lead Forming – With Option 2 Taping	1500 Units/Reel
SL(T3)	Surface Mount (Low Profile) Lead Forming– With Option 3 Taping	1000 Units/Reel
SL(T4)	Surface Mount (Low Profile) Lead Forming – With Option 4 Taping	1000 Units/Reel
SLM(T1)	Surface Mount (Gullwing) Lead Forming– With Option 1 Taping	1500 Units/Reel
SLM(T2)	Surface Mount (Gullwing) Lead Forming – With Option 2 Taping	1500 Units/Reel





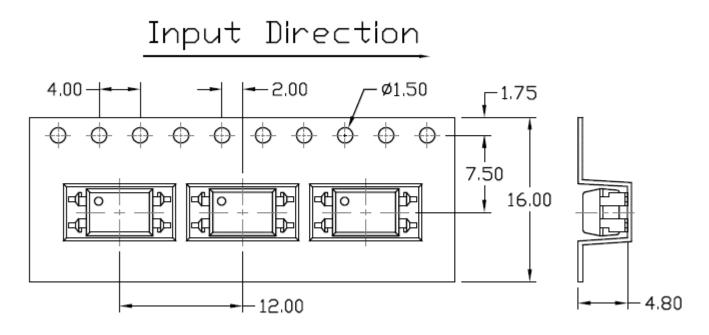


Option S(T2) & SL(T2)

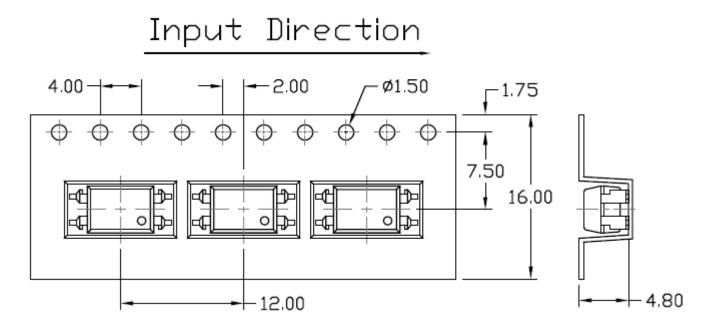




Option S(T3) & SL(T3)

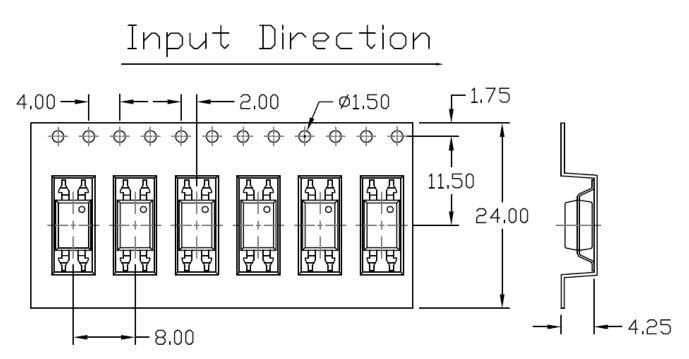


Option S(T4) & SL(T4)

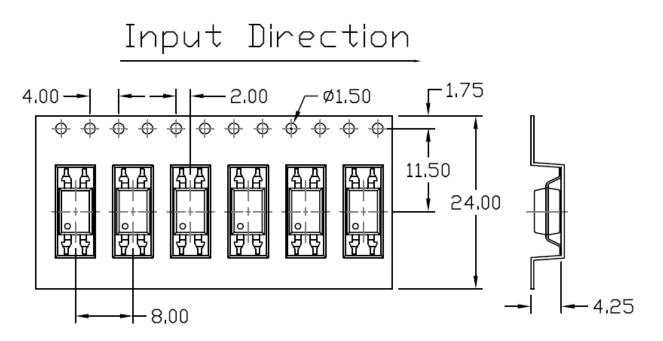




Option SLM(T1)



Option SLM(T2)





Wave soldering (follow the JEDEC standard JESD22-A111)

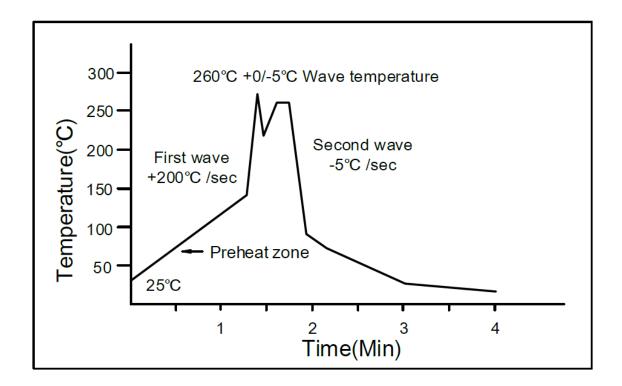
One time soldering is recommended within the condition of temperature.

Temperature: 260+0/-5°C.

Time: 10 sec.

Preheat temperature:25 to 140°C.

Preheat time: 30 to 80 sec.

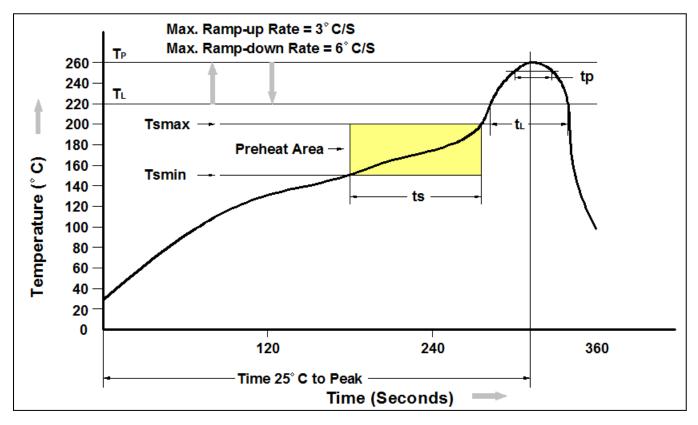


Iron soldering (follow the standard MIL-STD 202G, Method 210F)

Allow single lead soldering in every single process. One time soldering is recommended. Temperature: 350+±10℃ Time: 5 sec max.



Reflow Profile



Profile Feature	Pb-Free Assembly Profile			
Temperature Min. (Tsmin)	150°C			
Temperature Max. (Tsmax)	200°C			
Time (ts) from (Tsmin to Tsmax)	60-120 seconds			
Ramp-up Rate (t∟ to t⊳)	3°C/second max.			
Liquidous Temperature (T _L)	217°C			
Time (t _L) Maintained Above (T _L)	60 – 150 seconds			
Peak Body Package Temperature	260°C +0°C / -5°C			
Time (t₂) within 5°C of 260°C	30 seconds			
Ramp-down Rate $(T_P \text{ to } T_L)$	6°C/second max			
Time 25°C to Peak Temperature	8 minutes max.			



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